TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type

2SK2162

Audio-Frequency Power Amplifier Applications

High breakdown voltage: V_{DSS} = 180 V

• High forward transfer admittance: |Yfs| = 0.7 S (typ.)

• Complementary to 2SJ338

Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Drain-source voltage	V_{DSS}	180	V
Gate-source voltage	V_{GSS}	±20	V
Drain current (Note 1)	ID	1	Α
Power dissipation (Tc = 25°C)	P_{D}	20	W
Channel temperature	T _{ch}	150	°C
Storage temperature range	T _{stg}	-55~150	°C

Note 1: Ensure that the channel temperature does not exceed 150°C.

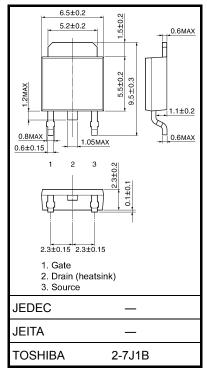
Note 2: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Unit: mm 6.8MAX 5.2±0.2 **0.6MAX** 0.95MAX 0.6±0.15 ∐ 0.6мах 2 1.1±0.2 1. Gate 2. Drain (heatsink) 3. Source JEDEC **JEITA** SC-64

2-7B1B

Weight: 0.36 g (typ.)

TOSHIBA



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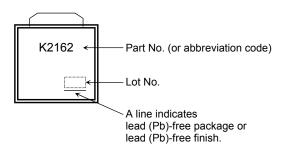


Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$	_	_	±100	nA
Drain-source breakdown voltage	V (BR) DSS	$I_D = 10$ mA, $V_{GS} = 0$ V	180	_	_	V
Gate-source cutoff current	V _{GS} (OFF)	V _{DS} = 10 V, I _D = 10 mA	1.4	_	2.8	V
Drain-source saturation voltage	V _{DS} (ON)	I _D = 0.6 A, V _{GS} = 10 V	_	1.7	3.0	V
Forward transfer admittance	Y _{fs}	V _{DS} = 10 V, I _D = 0.3 A	_	0.7	_	S
Input capacitance	C _{iss}		_	170	_	pF
Output capacitance	C _{oss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	_	45	_	pF
Reverse transfer capacitance	C _{rss}		_	17	_	pF

This transistor is an electrostatic-sensitive device. Handle with care.

Marking



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20070701-EN

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